TOSHIBA 1SS361F

## TOSHIBA DIODE SILICON EPITAXIAL PLANAR TYPE

# 1 S S 3 6 1 F

#### ULTRA HIGH SPEED SWITCHING APPLICATIONS

Small Package : 1608 Flat Lead

Excellent in Forward Current and Forward Voltage

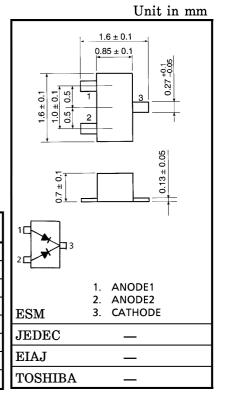
Characteristics  $: V_{F(3)} = 0.9 V \text{ (Typ.)}$ 

Fast Reverse Recovery Time :  $t_{rr} = 1.6 \text{ ns}$  (Typ.)

Small Total Capacitance  $: C_T = 0.9 \, pF \, (Typ.)$ 

### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Maximum (Peak) Reverse Voltage	$V_{RM}$	85	V
Reverse Voltage	$V_{\mathbf{R}}$	80	V
Maximum (Peak) Forward Current	$I_{FM}$	300 (*)	mA
Average Forward Current	IO	100 (*)	mA
Surge Current (10ms)	$I_{FSM}$	2 (*)	Α
Power Dissipation	P	100	mW
Junction Temperature	$T_j$	125	$^{\circ}\mathrm{C}$
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~125	°C



(\*) Unit Rating. Total Rating = Unit Rating × 1.5

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward Voltage	$V_{\mathrm{F}(1)}$	$I_{ m F}=1~{ m mA}$	<u> </u>	0.60	<u> </u>	V
	$V_{F(2)}$	$I_{ m F}=10{ m mA}$	_	0.72	<b>-</b>	
	$V_{F(3)}$	$I_{ m F}=100~{ m mA}$	_	0.90	1.20	
Reverse Current $\frac{IR(1)}{IR(2)}$	I <sub>R (1)</sub>	$V_R = 30 V$	_	_	0.1	$\mu$ A
	I <sub>R (2)</sub>	$V_R = 80 V$	_	_	0.5	
Total Capacitance	$\mathrm{C}_{\mathrm{T}}$	$V_{ m R}=0,~{ m f}=1~{ m MHz}$	_	0.9	3.0	pF
Reverse Recovery Time	$f_{\mathrm{T}}$	$I_F = 10 \text{mA}$ (Fig.1)	_	1.6	4.0	ns

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